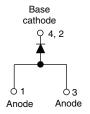


Vishay Semiconductors

Schottky Rectifier, 3.0 A



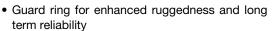


D-PAK	(TO-252AA)	
D . A	(10 202777)	

PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	3.0 A						
V _R	20 V, 30 V, 40 V						
V _F at I _F	0.49 V						
I _{RM}	20 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Single die						
E _{AS}	8 mJ						

FEATURES

• Low forward voltage drop





Halogen-free according to IEC 61249-2-21 definition

HALOGEN FREE

- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-MBRD320-M3, VS-MBRD330-M3, VS-MBRD340-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATING	MAJOR RATINGS AND CHARACTERISTICS											
SYMBOL	CHARACTERISTICS	VALUES	UNITS									
I _{F(AV)}	Rectangular waveform	3.0	Α									
V _{RRM}		20 to 40	V									
I _{FSM}	t _p = 5 µs sine	490	Α									
V _F	3 Apk, T _J = 125 °C	0.49	V									
T _J		- 40 to 150	°C									

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBRD320-M3	VS-MBRD330-M3	VS-MBRD340-M3	UNITS				
Maximum DC reverse voltage	V_{R}	20	30	40	V				
Maximum working peak reverse voltage	V_{RWM}	20	30	40	V				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _L = 133 °C, rectangular waveform		3.0					
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	490	Α				
non-repetitive surge current	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	75					
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 16 mH		8.0	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	А				

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Schottky Rectifier, 3.0 A



Document Number: 93323

Revision: 03-Nov-10

ELECTRICAL SPECIFICAT	ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			UNITS				
		3 A	T _{.1} = 25 °C	0.48	0.6					
Maximum forward voltage drop	V _{FM} ⁽¹⁾	6 A	T _J = 25 °C	0.58	0.7	v				
See fig. 1	VFM ('')	3 A		0.41	0.49	V				
		6 A	1j=125 C	0.55	0.625					
Maximum reverse leakage current	I _{RM} ⁽¹⁾	$T_J = 25 ^{\circ}\text{C}$		0.02	0.2	mA				
See fig. 2	I_{RM} (1) I_{RM} (1) $V_R = Rated V_R$		10.7	20	IIIA					
Typical junction capacitance	C _T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C		189	-	pF				
Typical series inductance	L _S	Measured lead to lead 5 n	5.0	-	nH					
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs				

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL	THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS							
Maximum junction temperature range	T _J ⁽¹⁾		- 40 to 150	°C							
Maximum storage temperature range	T_{Stg}		- 40 to 175	C							
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	6.0	°C 111							
Maximum thermal resistance, junction to ambient	R _{thJA}		80	°C/W							
Approximate weight			0.3	g							
Approximate weight			0.01	oz.							
			MBR	D320							
Marking device		Case style D-PAK (similar to TO-252AA)	MBRD330								
			MBRD340								

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



Schottky Rectifier, 3.0 A

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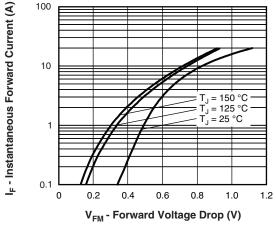


Fig. 1 - Maximum Forward Voltage Drop Characteristics

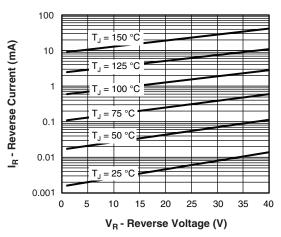


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

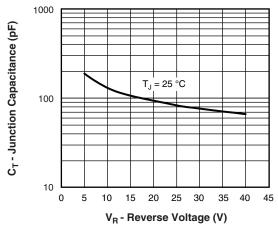


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

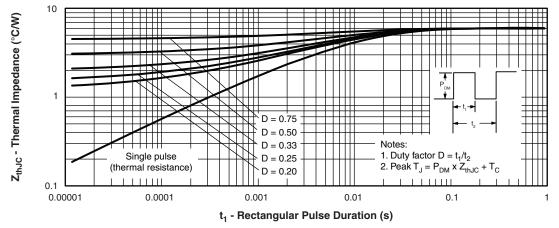


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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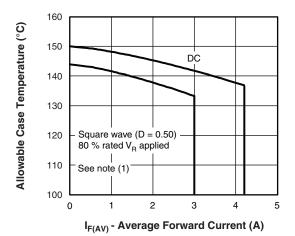


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

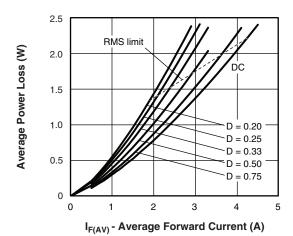


Fig. 6 - Forward Power Loss Characteristics

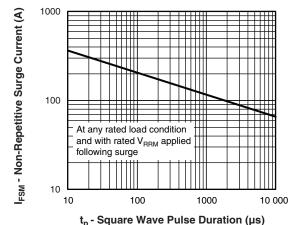


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

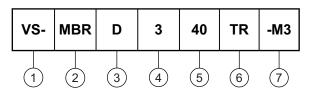


Schottky Rectifier, 3.0 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Schottky MBR series

- D = TO-252AA (D-PAK)

- Current rating (3 = 3 A)

Voltage ratings 20 = 20 V Voltage ratings 30 = 30 V 40 = 40 V

6 - • None = Tube

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

7 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATI	ORDERING INFORMATION (Example)										
PREFERRED P/N	PREFERRED P/N QUANTITY PER T/R		PACKAGING DESCRIPTION								
VS-MBRD320-M3	75	3000	Antistatic plastic tube								
VS-MBRD320TR-M3	2000	2000	13" diameter reel								
VS-MBRD320TRL-M3	3000	3000	13" diameter reel								
VS-MBRD320TRR-M3	3000	3000	13" diameter reel								
VS-MBRD330-M3	75	3000	Antistatic plastic tube								
VS-MBRD330TR-M3	2000	2000	13" diameter reel								
VS-MBRD330TRL-M3	3000	3000	13" diameter reel								
VS-MBRD330TRR-M3	3000	3000	13" diameter reel								
VS-MBRD340-M3	75	3000	Antistatic plastic tube								
VS-MBRD340TR-M3	2000	2000	13" diameter reel								
VS-MBRD340TRL-M3	3000	3000	13" diameter reel								
VS-MBRD340TRR-M3	3000	3000	13" diameter reel								

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95016				
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				



Vishay Semiconductors

INCHES

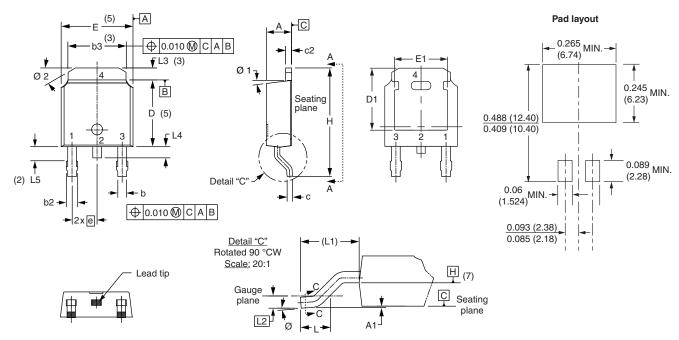
MIN.

MAX.

NOTES

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDOL	MIN.	MAX.
Α	2.18	2.39	0.086	0.094			е	2.29	BSC
A1	-	0.13	-	0.005			Н	9.40	10.41
b	0.64	0.89	0.025	0.035			L	1.40	1.78
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC
С	0.46	0.61	0.018	0.024			L3	0.89	1.27
c2	0.46	0.89	0.018	0.035			L4	-	1.02
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52
D1	5.21	-	0.205	-	3		Ø	0°	10°
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°
E1	4.32	-	0.170	-	3		Ø2	25°	35°

е	2.29 BSC		0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74	BSC	0.108	REF.	
L2	0.51	BSC	0.020	BSC	
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	·
Ø2	25°	35°	25°	35°	·
	H L1 L2 L3 L4 L5 Ø	H 9.40 L 1.40 L1 2.74 L2 0.51 L3 0.89 L4 - L5 1.14 Ø 0° Ø1 0°	H 9.40 10.41 L 1.40 1.78 L1 2.74 BSC L2 0.51 BSC L3 0.89 1.27 L4 - 1.02 L5 1.14 1.52 Ø 0° 10° Ø1 0° 15°	H 9.40 10.41 0.370 L 1.40 1.78 0.055 L1 2.74 BSC 0.108 L2 0.51 BSC 0.020 L3 0.89 1.27 0.035 L4 - 1.02 - L5 1.14 1.52 0.045 Ø 0° 10° 0° Ø1 0° 15° 0°	H 9.40 10.41 0.370 0.410 L 1.40 1.78 0.055 0.070 L1 2.74 BSC 0.108 REF. L2 0.51 BSC 0.020 BSC L3 0.89 1.27 0.035 0.050 L4 - 1.02 - 0.040 L5 1.14 1.52 0.045 0.060 Ø 0° 10° 0° 10° Ø1 0° 15° 0° 15°

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



Legal Disclaimer Notice

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000